



#### 60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON) MAX</sub>	I <sub>D MAX</sub> T <sub>C</sub> = +25°C (Note 9)
60V	$6.5 \text{m}\Omega$ @ $V_{GS} = 10V$	100A
	$10m\Omega$ @ $V_{GS} = 4.5V$	81.6A

### **Features**

- Rated to +175°C —Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching(UIS) Test in Production-Ensures More Reliable and Robust End Application
- Low R<sub>DS(ON)</sub>—Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

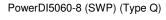
# **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- **Engine Management Systems**
- **Body Control Electronics**
- DC-DC Converters

#### **Mechanical Data**

- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe: Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)

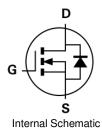


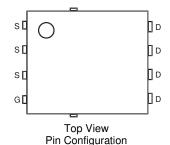






**Bottom View** 





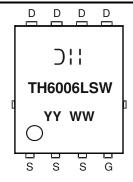
#### Ordering Information (Note 4)

Part Number	Case	Packaging	
DMTH6006LPSW-13	PowerDI5060-8 (SWP) (Type Q)	2500/Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

# **Marking Information**



⊃ ! ! = Manufacturer's Marking TH6006LSW = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)



# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage		V <sub>DSS</sub>	60	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
Continuous Dunin Comment V 10V (Note 5)	T <sub>A</sub> = +25°C	I <sub>D</sub>	17.2	^	
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 5)	$T_A = +100^{\circ}C$		12.1	Α Α	
	T <sub>C</sub> = +25°C	I <sub>D</sub>	100	А	
Continuous Drain Current, V <sub>GS</sub> = 10V (Notes 6 and 9)	T <sub>C</sub> = +100°C		71.6		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	400	Α	
Maximum Continuous Body Diode Forward Current (Note	Is	100	Α		
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cy	I <sub>SM</sub>	400	Α		
Avalanche Current, L=0.1mH	I <sub>AS</sub>	28.5	Α		
Avalanche Energy, L=0.1mH	E <sub>AS</sub>	40.7	mJ		

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25$ °C	$P_{D}$	2.88	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ heta JA}$	52	°C/W
Total Power Dissipation (Note 6)	$T_C = +25^{\circ}C$	$P_{D}$	100	W
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	1.5	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +175	°C

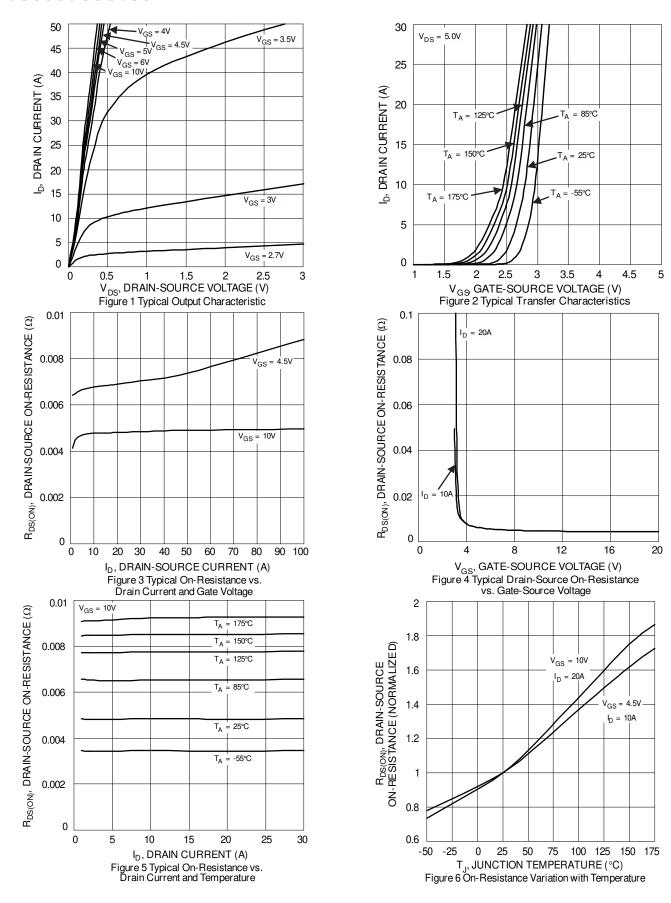
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)		•		•		•	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0V$ , $I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.2	_	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Chatia Dunin Course On Bonistones		_	4.9	6.5	0	V <sub>GS</sub> = 10V, I <sub>D</sub> = 20A	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		7.1	10	mΩ	$V_{GS} = 4.5V, I_D = 10A$	
Diode Forward Voltage	V <sub>SD</sub>		0.8	1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 20A	
DYNAMIC CHARACTERISTICS (Note 8)		•	•	•		•	
Input Capacitance	C <sub>iss</sub>	_	2162	_		$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	_	761	_	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	58	_			
Gate Resistance	Rg	_	0.7	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qq	_	18.1	_			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	34.9	_	nC	$V_{DS} = 30V, I_D = 20A$	
Gate-Source Charge	Q <sub>gs</sub>	_	6.1	_	IIC		
Gate-Drain Charge	Q <sub>gd</sub>	_	7.3	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.0	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_{D} = 20A, R_{q} = 3\Omega$	
Turn-On Rise Time	t <sub>R</sub>	_	5.4	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	20.4	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	7.8	_			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	35.8	_	ns	1 00 A 11/-14 4 00 A /	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	40.2	_	nC	I <sub>F</sub> = 20A, di/dt = 100A/μs	

Notes:

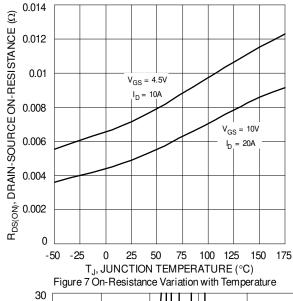
- 5. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
- 6. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.
- 9. Limited by package.

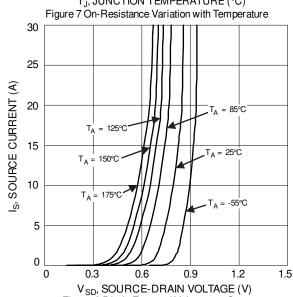


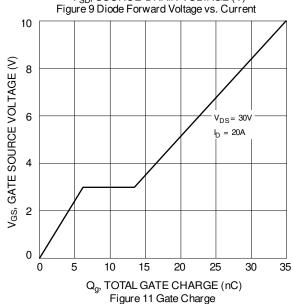


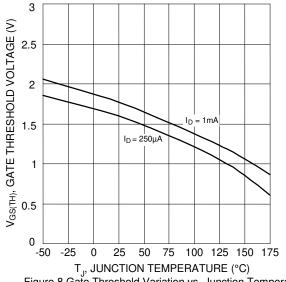


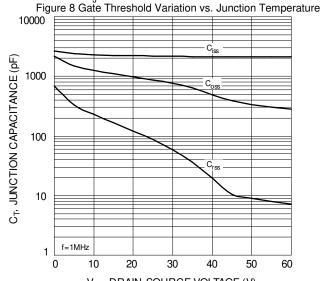


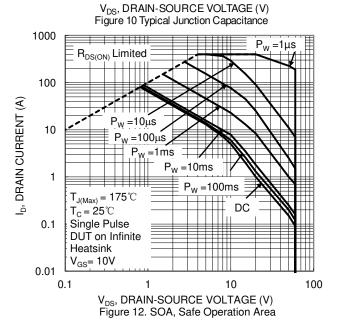




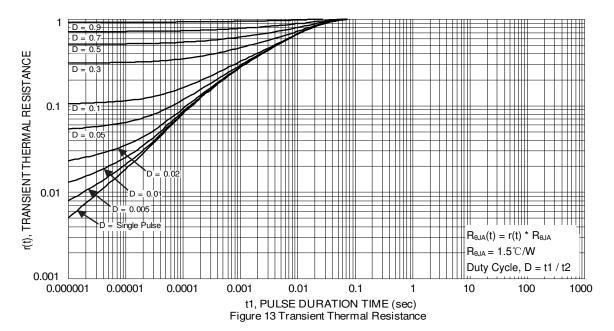








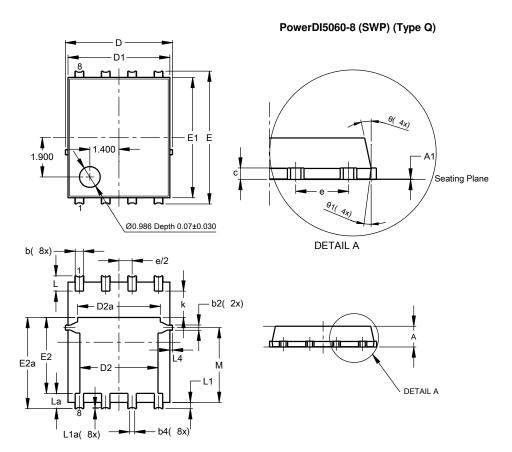






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

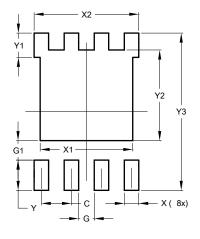


PowerDI5060-8 (SWP) (Type Q)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	C	).25REF		
C	0.230	0.330	0.277	
D		.15 BS0	)	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
Е	6	.40 BS0		
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1.27BSC			
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0.050REF			
L4	0.025	0.225	0.125	
М	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI5060-8 (SWP) (Type Q)



Dimensions	Value		
Dilliensions	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	4.420		
Υ	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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